

ESD9X5VL

1-Line, Uni-directional, Ultra-low Capacitance Transient Voltage Suppressor

Descriptions

The ESD9X5VL is a Uni-directional transient voltage suppressor (TVS) which provide a very high level protection for sensitive electronic components that may be subjected to electrostatic discharge (ESD). It is designed to replace multilayer varistors (MLV) in consumer equipments applications such as mobile phone, notebook, PAD, STB, LCD TV etc.

The ESD9X5VL incorporates one pair of ultra-low capacitance steering diodes plus a TVS diode.

The ESD9X5VL may be used to provide ESD protection up to ± 20 kV (contact and air discharge) according to IEC61000-4-2, and withstand peak pulse current up to 4A for 8/20µs pulse according to IEC61000-4-5.

The ESD9X5VL is available in FBP-02C package. Standard products are Pb-free and Halogen-free.

Features

- Stand-off voltage: 5V max.
- Transient protection for each line according to IEC61000-4-2 (ESD): ±20kV (contact and air discharge) IEC61000-4-4 (EFT): 40A (5/50ns)
 IEC61000-4-5 (surge): 4A (8/20µs)
- Ultra-low capacitance: $C_J = 1.2pF$ typ.
- Ultra-low leakage current: I_R <1nA typ.
- Low clamping voltage: V_{CL} = 18V typ. @ I_{PP} = 16A (TLP)
- Solid-state silicon technology

Applications

- USB 2.0 and USB 3.0
- HDMI 1.3 and HDMI 1.4
- SATA and eSATA
- DVI
- IEEE 1394
- PCI Express
- Portable Electronics and Notebooks

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FBP-02C (Bottom View)





Order information

Device	Package	Shipping
ESD9X5VL-2/TR	FBP-02C	10000/Tape&Reel



Absolute maximum ratings

Parameter	Symbol	Rating	Unit	
Peak pulse power ($t_p = 8/20\mu s$)	P _{pk}	60	W	
Peak pulse current ($t_p = 8/20\mu s$)	I _{PP}	4	А	
ESD according to IEC61000-4-2 air discharge		±20	kV	
ESD according to IEC61000-4-2 contact discharge	- V _{ESD}	±20		
Junction temperature	TJ	125	°C	
Operation temperature	T _{OP}	-40~85	°C	
Lead temperature	TL	260	°C	
Storage temperature	T _{STG}	-55~150	°C	

Electrical characteristics (T_A = 25 °C, unless otherwise noted)

Parameter	Symbol	Condition	Min.	Тур.	Max.	Unit
Reverse maximum working voltage	V _{RWM}				5.0	V
Reverse leakage current	I _R	$V_{RWM} = 5V$		<1	100	nA
Reverse breakdown voltage	V_{BR}	I _{BR} = 1mA	7.0	8.0	9.0	V
Forward voltage	V _F	I _F = 10mA	0.6	0.9	1.2	V
Clamping voltage ¹⁾	V _{CL}	I _{PP} = 16A, t _p = 100ns		18.0		V
Dynamic resistance 1)	R _{DYN}			0.59		Ω
Clamping voltage ²⁾	V _{CL}	$I_{PP} = 1A, t_p = 8/20\mu s$			11.0	V
		$I_{PP} = 4A, t_p = 8/20 \mu s$			15.0	V
Junction capacitance	CJ	$V_R = 0V$, f = 1MHz		1.2	1.6	pF

Notes:

1) TLP parameter: $Z_0 = 50 \Omega$, $t_p = 100$ ns, $t_r = 2$ ns, averaging window from 60 ns to 80 ns. R_{DYN} is calculated from 4A to 16A.

2) Non-repetitive current pulse, according to IEC61000-4-5.



Typical characteristics (T_A = 25 °C, unless otherwise noted)





Contact discharge current waveform per IEC61000-4-2



Clamping voltage vs. Peak pulse current



Non-repetitive peak pulse power vs. Pulse time

Capacitance vs. Reverse voltage



Power derating vs. Ambient temperature



Typical characteristics (T_A = 25 °C, unless otherwise noted)



20ns/div

ESD clamping (+8kV contact discharge per IEC61000-4-2)



TLP Measurement



ESD clamping (-8kV contact discharge per IEC61000-4-2)



Package outline dimensions

FBP-02C



Top View



Side View



Recommend land pattern (Unit: mm)



Bottom View

Symbol	Dimensions In Millimeters			
	Min.	Тур.	Max.	
А	0.450	0.500	0.550	
A1	0.010		0.100	
D	0.950	1.000	1.050	
E	0.550	0.600	0.650	
D1	0.470 Ref.			
E1	0.420 Ref.			
b	0.270	0.320	0.370	
b1	0.250	0.300	0.350	
е	0.555	0.605	0.655	
e1	0.230 Ref.			
L	0.250	0.300	0.350	
L1	0.030 Ref.			
L2	0.370	0.420	0.470	
L3	0.040 Ref.			

Notes:

This recommended land pattern is for reference purposes only. Please consult your manufacturing group to ensure your PCB design guidelines are met.